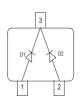


Silicon Variable Capacitance Diodes

- For FM radio tuners with extended frequency band
- High tuning ratio at low supply voltage (car radio)
- Monolithic chip (common cathode) for perfect dual diode tracking
- Coded capacitance groups and group matching available
- Pb-free (RoHS compliant) package



BB814

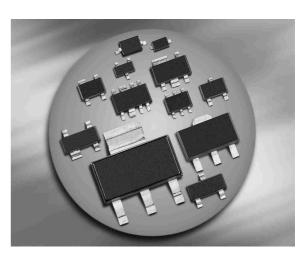


Туре	Package	Configuration	L_S (nH)	Marking
BB814	SOT23	common cathode	1.8	SH1/2*

*For differences see next page Capacitance groups

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit	
Diode reverse voltage	V _R	18	V	
Peak reverse voltage-	V _{RM}	20		
Forward current	I _F	50	mA	
Operating temperature range	T _{op}	-55 125	°C	
Storage temperature	T _{sta}	-55 150		





Parameter	Symbol	Values			Unit
		min.	typ.	max.	1
DC Characteristics					
Reverse current	I _R				nA
<i>V</i> _R = 16 V		-	-	20	
<i>V</i> _R = 16 V, <i>T</i> _A = 60 °C		-	-	200	
AC Characteristics					
Diode capacitance ¹⁾	CT				pF
<i>V</i> _R = 2 V, <i>f</i> = 1 MHz		43	44.75	46.5	
V _R = 8 V, <i>f</i> = 1 MHz		19.1	20.8	22.7	
Capacitance ratio	C _{T2} /C _{T8}	2.05	2.15	2.25	
V _R = 2 V, V _R = 8 V, <i>f</i> = 1 MHz					
Capacitance matching ²⁾	∆C _T /C _T	-	-	3	%
$V_{\rm R}$ = 2 V, $V_{\rm R}$ = 8 V, f = 1 MHz					
Series resistance	r _S	-	0.18	-	Ω
V _R = 2 V, <i>f</i> = 100 MHz					
Q factor	Q	-	200	-	
<i>f</i> = 100 MHz, <i>V</i> _R = 2 V					

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

 $^{1}Capacitance groups at 2V and 8V, coded 1; 2 <math display="inline">C_{T}/groups$ 1 2

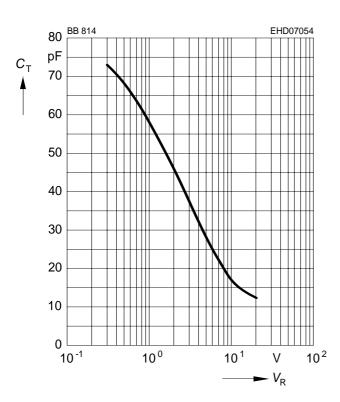
C _{2V}	min	43pF	44.5pF
C _{2V}	max	45pF	46.5pF
C _{8V}	min	19.1pF	19.75pF
C _{8V}	max	21.95pF	22.7pF

²For details please refer to Application Note 047.



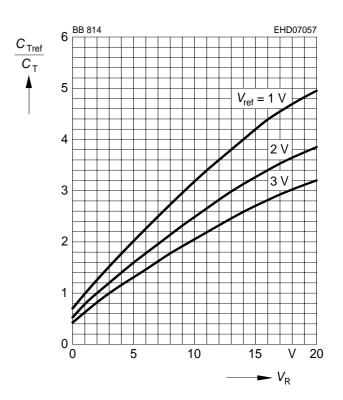
Diode capacitance $C_{T} = f(V_{R})$

f = 1MHz

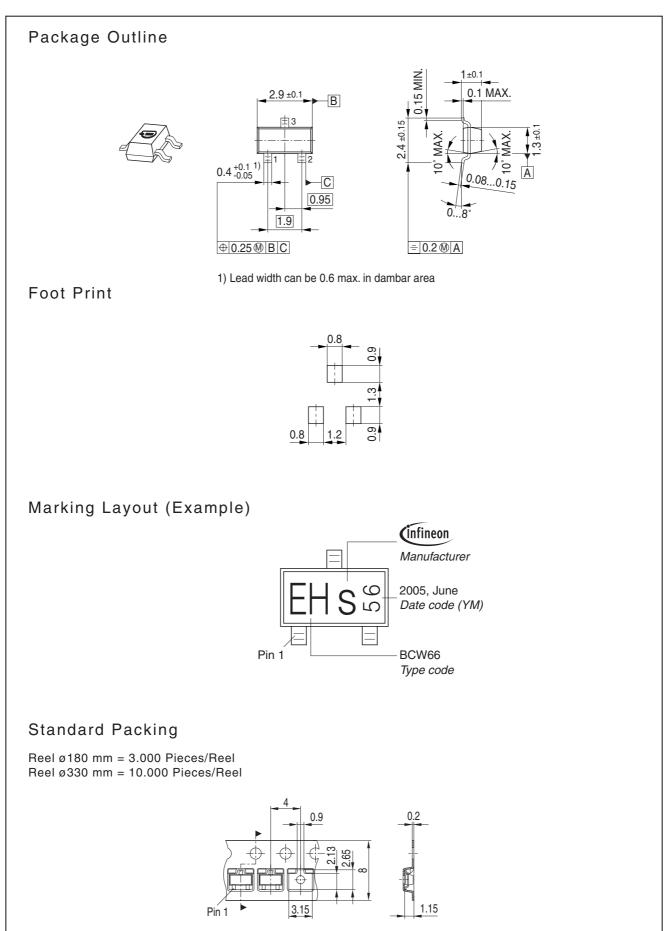


Capacitance ratio $C_{\text{Tref}}/C_{\text{T}} = f(V_{\text{R}})$

f = 1 MHz









Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

© 2009 Infineon Technologies AG All Rights Reserved.

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (<<u>www.infineon.com</u>>).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered. 单击下面可查看定价,库存,交付和生命周期等信息

>>Infineon(英飞凌)